

QUAD OPERATIONAL AMPLIFIER

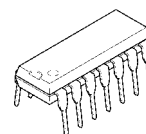
■ GENERAL DESCRIPTION

NJM2745 is quad operational amplifier with low voltage noise $5\text{nV}/\sqrt{\text{Hz}} (@f=1\text{kHz})$ with high bandwidth and low distortion.

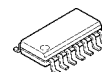
These features may be used in audio signal processing by high-level audio usages such as hi-end car audio, high-quality TV set and others.

In addition, these also suitable for audio mixer, studio-recording equipments, broadcasting equipments, and the usages in various professional sound equipments.

■ PACKAGE OUTLINE



NJM2745D



NJM2745M

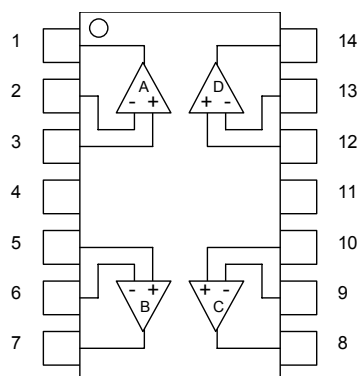


NJM2745V

■ FEATURES

- Low Input Noise Voltage $5\text{nV}/\sqrt{\text{Hz}}$ typ
- Wide Gain Bandwidth Product 15MHz typ
- Low Distortion 0.0005% typ
- Slew Rate $5\text{V}/\mu\text{s}$ typ
- Operating Voltage $\pm 2\text{V}$ to $\pm 15.5\text{V}$ (DIP Package)
 $\pm 2\text{V}$ to $\pm 9.5\text{V}$ (DMP/SSOP Package)
- Package Outline
NJM2745D : DIP14, NJM2745M : DMP14
NJM2745V : SSOP14
- Bipolar Technology

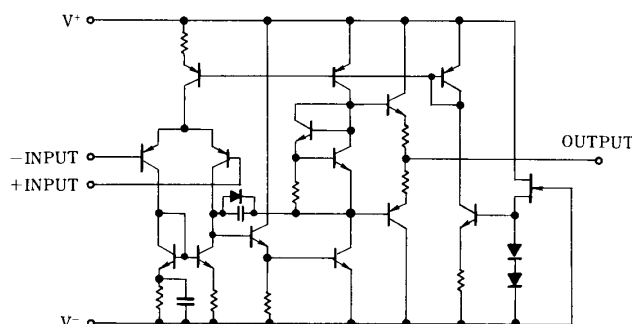
■ PIN CONFIGURATION



PIN ASSIGNMENT

- | | |
|-------------|--------------|
| 1. A OUTPUT | 8. C OUTPUT |
| 2. A -INPUT | 9. C -INPUT |
| 3. A +INPUT | 10. C +INPUT |
| 4. V+ | 11. V- |
| 5. B +INPUT | 12. D +INPUT |
| 6. B -INPUT | 13. D -INPUT |
| 7. B OUTPUT | 14. D OUTPUT |

■ EQUIVALENT CIRCUIT (1/4 Shown)



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V^+ / V^-	±18 [DIP14], ±16 [DMP14, SSOP14]	V
Common Mode Input Voltage Range	V_{ICM}	±15 [DIP14] (Note 1), ±13 [DMP14, SSOP14] (Note 1)	V
Differential Input Voltage Range	V_{ID}	±30 [DIP14] (Note 1), ±26 [DMP14, SSOP14] (Note 1)	V
Power Dissipation	P_D	870 [DIP14] 700 [DMP14] (Note 2) 570 [SSOP14] (Note 2)	mW
Load Current	I_O	±50 (Note3, Note 4)	mA
Operating Temperature Range	T_{opr}	-40~+85	°C
Storage Temperature Range	T_{stg}	-40~+150	°C

(Note 1) For supply voltages less than "Absolute Maximum Ratings", the absolute maximum input voltage is equal to the supply voltage.

(Note 2) Mounted on the EIA/JEDEC standard board (76.2×114.3×1.6mm, two layer FR-4).

(Note 3) It individually takes the absolute value of the sink current and the source current of each output terminal, and it is assumed the sum total. Calculation type: $I_O = |I_{AOUTPUT}| + |I_{BOUTPUT}| + |I_{COUTPUT}| + |I_{DOUTPUT}|$

(Note 4) Please note the supply current when the load is short-circuited.

■ RECOMMENDATION OPERATING CONDITION

(Ta=25°C)

PARAMETER	SYMBOL	PACKAGE	RATINGS	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V^+ / V^-	DIP14	(Note 2, Note 5, Note 6) $R_L \geq 10k\Omega$	±2	-	±15.5	V
		DMP14, SSOP14	(Note 2, Note 5, Note 6) $R_L \geq 10k\Omega$	±2	-	±9.5	

(Note 5) Do not exceed "Power dissipation: P_D " in which power dissipation in IC "Symbol: W" is shown by the absolute maximum rating.

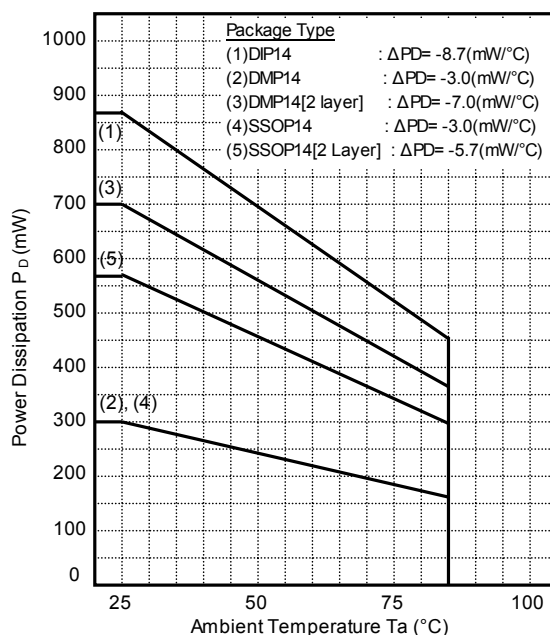
Please use it under the system requirements of NJM2745 to always satisfy "Condition: $P_D \geq W$ ".

The calculation type when using it in dual supplies is " $W = I_{CC} \times 2 \times V^+ + 1.62 \times (V^+ \times V^- + (2 \times R_L))$ ".

(Calculation type condition: Loads connected with an individual output terminal are this all characteristics, and it is assumed same resistance R_L)

(Note 6) Refer to following Figure 1 for a permissible loss when ambient temperature (T_a) is $T_a \geq 25^\circ\text{C}$.

FIGURE 1. Power Dissipation vs. Ambient Temperature



■ ELECTRIC CHARACTERISTICS [NJM2745D]

● DC CHARACTERISTICS [NJM2745D] ($V^+/V^- = \pm 15V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{CC}	No Signal	-	13	16	mA
Input Offset Voltage	V_{IO}	$R_S \leq 10k\Omega$	-	0.3	3	mV
Input Bias Current	I_B		-	100	500	nA
Input Offset Current	I_{IO}		-	5	200	nA
Large Signal Voltage Gain	A_V	$R_L \geq 2k\Omega, V_o = \pm 10V$	90	110	-	dB
Common Mode Rejection Ratio	CMR	$R_S \leq 10k\Omega, -12V \leq V_{IC} \leq +12V$	80	110	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10k\Omega, V^+/V^- = \pm 2 \sim \pm 15V$	80	110	-	dB
Maximum Output Voltage	V_{OM}	$R_L \geq 2k\Omega$	± 12	± 13.5	-	V
Input Common Mode Voltage Range	V_{ICM}	CMR $\geq 80dB$	-12	-	+12	V

● AC CHARACTERISTICS [NJM2745D] ($V^+/V^- = \pm 15V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Bandwidth	GB	$f = 10kHz$	-	15	-	MHz
Equivalent input Noise Voltage	V_{NI}	$R_S = 0\Omega$	-	5	-	nV/ $\sqrt{Hz}$
Total Harmonic Distortion	THD	$A_V = 20dB, V_o = 5V_{rms}$ $R_L = 2k\Omega, f = 1kHz$	-	0.0005	-	%

● TRANSIENT CHARACTERISTICS [NJM2745D] ($V^+/V^- = \pm 15V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	$R_L \geq 2k\Omega$	-	5	-	V/ μs

■ ELECTRIC CHARACTERISTICS [NJM2745M / NJM2745V]

● DC CHARACTERISTICS [NJM2745M / NJM2745V] ($V^+/V^- = \pm 4.5V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{CC}	No Signal	-	12	16	mA
Input Offset Voltage	V_{IO}	$R_S \leq 10k\Omega$	-	0.3	3	mV
Input Bias Current	I_B		-	100	500	nA
Input Offset Current	I_{IO}		-	5	200	nA
Large Signal Voltage Gain	A_V	$R_L \geq 2k\Omega, V_o = \pm 1.5V$	90	110	-	dB
Common Mode Rejection Ratio	CMR	$R_S \leq 10k\Omega, -2.5V \leq V_{IC} \leq +2.5V$	70	110	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10k\Omega, V^+/V^- = \pm 2 \sim \pm 7V$	80	110	-	dB
Maximum Output Voltage	V_{OM}	$R_L \geq 2k\Omega$	± 2.5	± 3	-	V
Input Common Mode Voltage Range	V_{ICM}	CMR $\geq 70dB$	-2.5	-	+2.5	V

● AC CHARACTERISTICS [NJM2745M / NJM2745V] ($V^+/V^- = \pm 4.5V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Bandwidth	GB	$f = 10kHz$	-	15	-	MHz
Equivalent input Noise Voltage	V_{NI}	$R_S = 0\Omega$	-	5	-	nV/ $\sqrt{Hz}$
Total Harmonic Distortion	THD	$V^+/V^- = \pm 9V, A_V = 20dB, V_o = 4V_{rms}$ $R_L = 2k\Omega, f = 1kHz$ $V^+/V^- = \pm 4.5V, A_V = 20dB, V_o = 1V_{rms}$ $R_L = 2k\Omega, f = 1kHz$	-	0.001	-	%
			-	0.005	-	

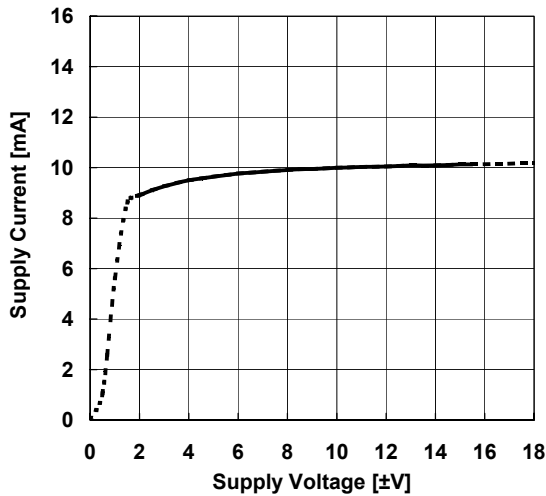
● TRANSIENT CHARACTERISTICS [NJM2745M / NJM2745V] ($V^+/V^- = \pm 4.5V, T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	$R_L \geq 2k\Omega$	-	5	-	V/ μs

■ TYPICAL CHARACTERISTICS

Supply Current vs. Supply Voltage

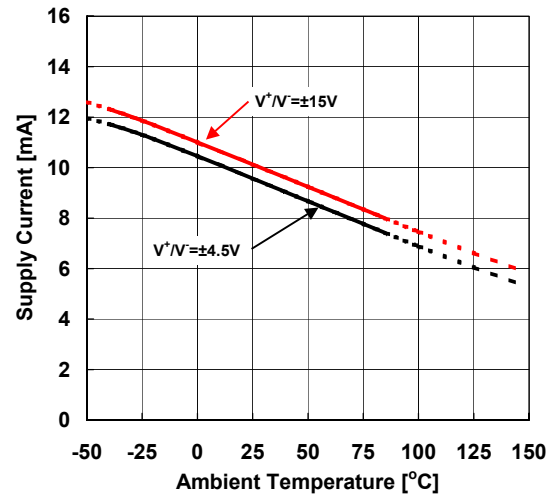
$V_{IN}=0V$, $T_a=25^\circ C$



Supply Current vs. Ambient Temperature

(Supply Voltage)

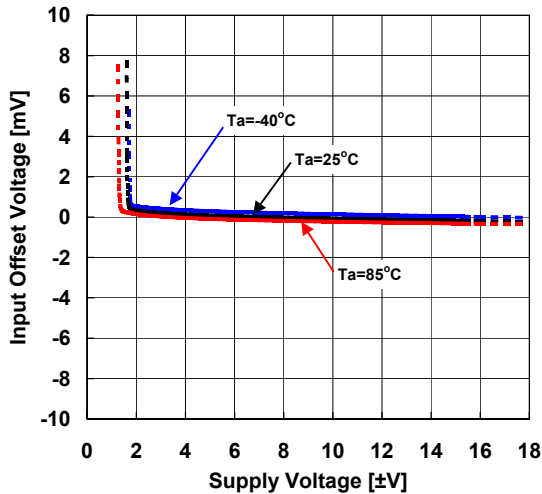
$V_{IN}=0V$



Input Offset Voltage vs. Supply Voltage

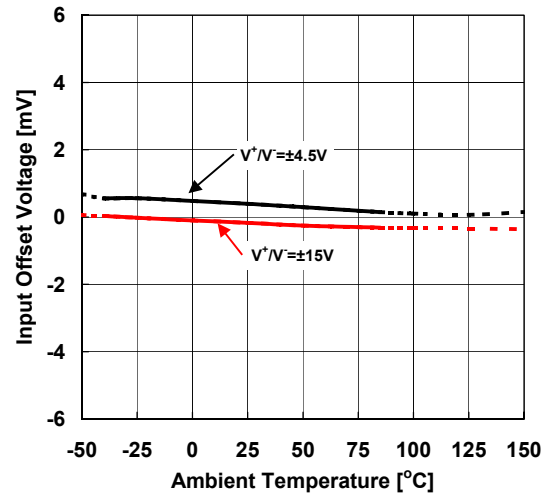
(Ambient Temperature)

$V_{ICM}=0V$, $R_S=10k\Omega$



Input Offset Voltage vs. Ambient Temperature

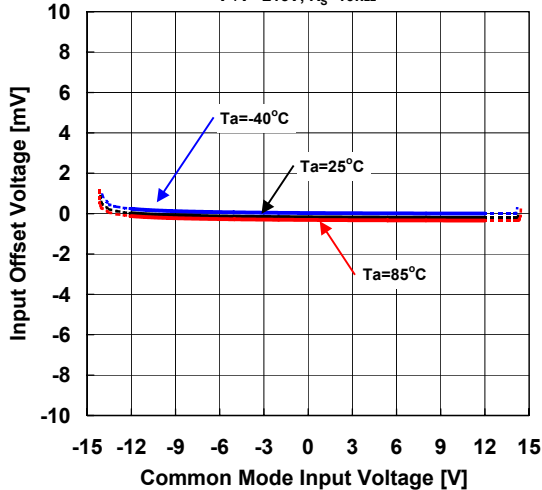
$V^+/V^-=\pm 15V$, $V_{ICM}=0V$



Input Offset Voltage vs. Common Mode Input Voltage

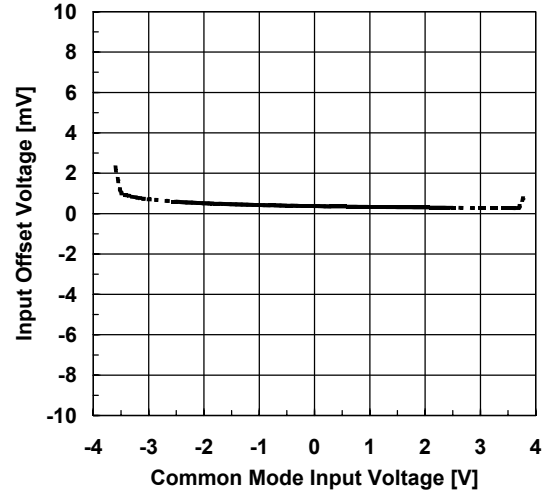
(Ambient Temperature)

$V^+/V^-=\pm 15V$, $R_S=10k\Omega$



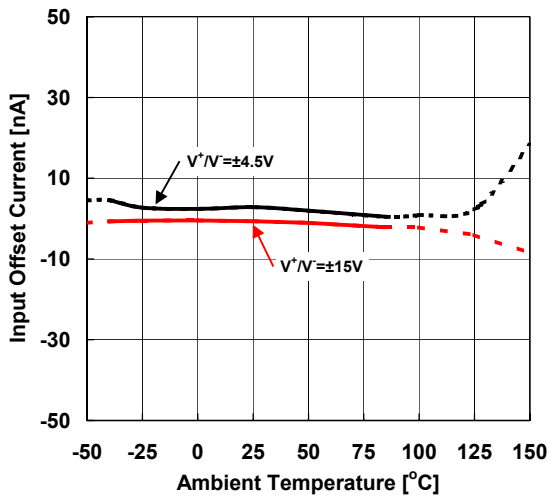
Input Offset Voltage vs. Common Mode Input Voltage

$V^+/V^-=\pm 4.5V$, $R_S=10k\Omega$, $T_a=25^\circ C$

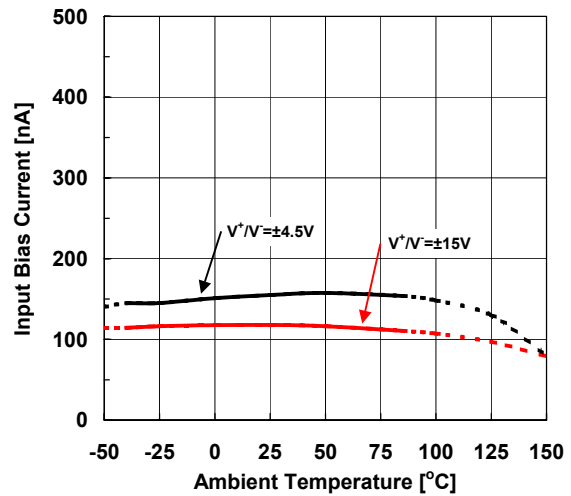


TYPICAL CHARACTERISTICS

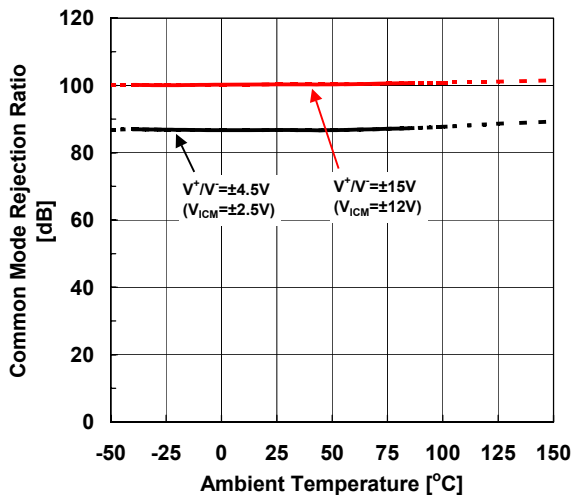
Input Offset Current vs. Ambient Temperature
 $V_{ICM}=0V$, $R_S=50k\Omega$



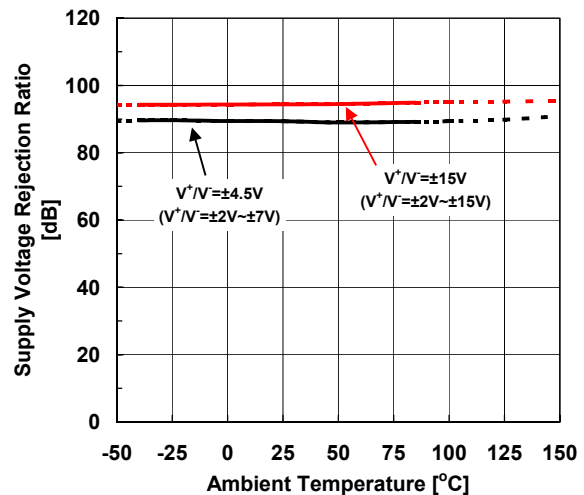
Input Bias Current vs. Ambient Temperature
 $V_{ICM}=0V$, $R_S=10k\Omega$



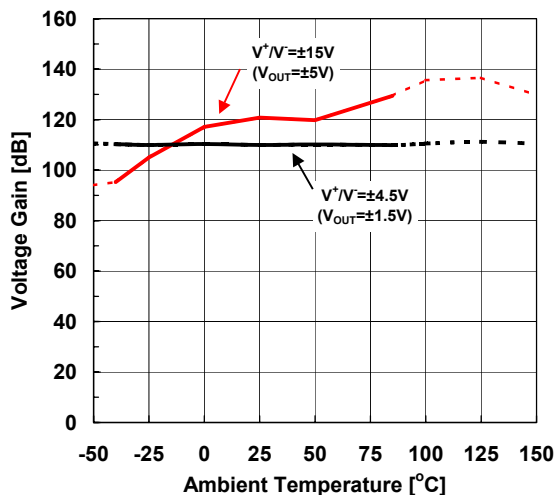
Common Mode Rejection Ratio
 vs. Ambient Temperature
 $R_S=10k\Omega$



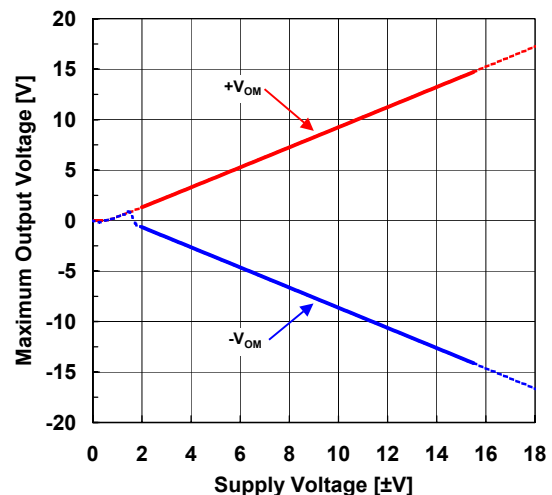
Supply Voltage Rejection Ratio
 vs. Ambient Temperature
 $R_S=10k\Omega$



Voltage Gain vs. Ambient Temperature
 $R_L=2k\Omega$



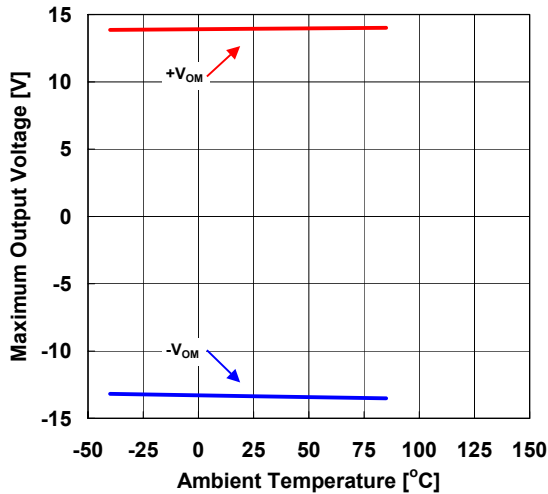
Maximum Output Voltage vs. Supply Voltage
 $V_{IN}=±1V$, $V_{IN}=0V$, $R_L=10k\Omega$, $T_a=25°C$



■ TYPICAL CHARACTERISTICS

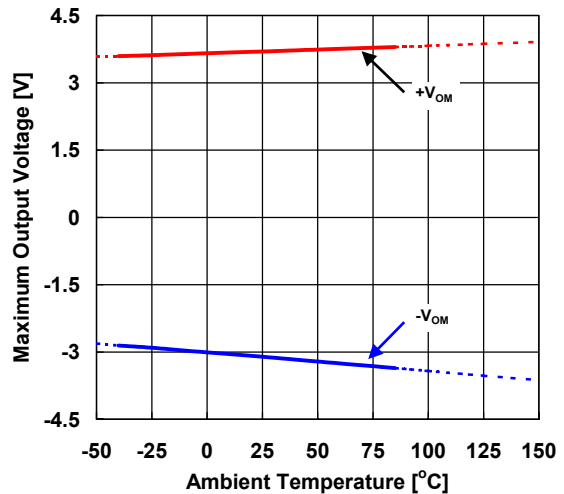
Maximum Output Voltage vs. Ambient Temperature

$V^+/V^- = \pm 15V$, $V_{IN} = \pm 1V$, $V_{IN} = 0V$, $R_L = 2k\Omega$



Maximum Output Voltage vs. Ambient Temperature

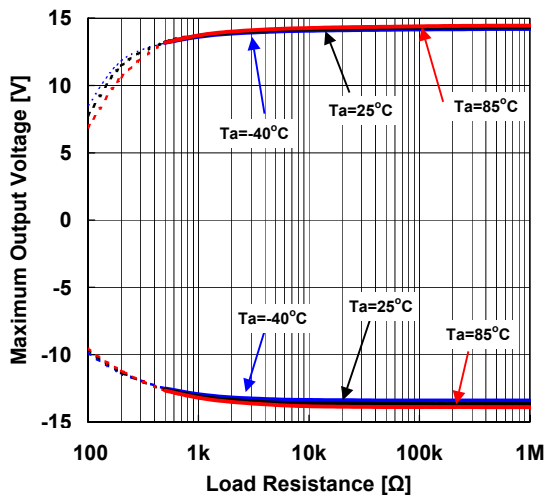
$V^+/V^- = \pm 4.5V$, $V_{IN} = \pm 1V$, $R_L = 2k\Omega$



Maximum Output Voltage vs. Load Resistance

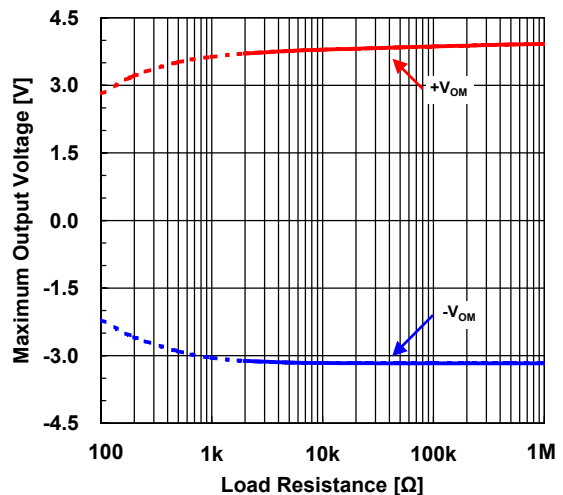
(Ambient Temperature)

$V^+/V^- = \pm 15V$, $V_{IN} = \pm 1V$, $V_{IN} = 0V$



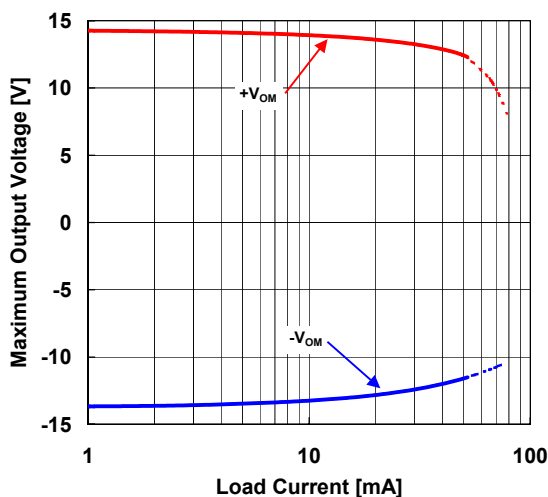
Maximum Output Voltage vs. Load Resistance

$V^+/V^- = \pm 4.5V$, $V_{IN} = \pm 1V$, $T_a = 25^\circ C$



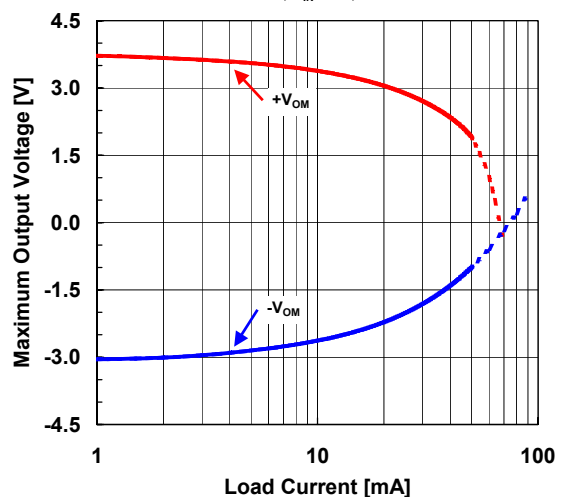
Maximum Output Voltage vs. Load Current

$V^+/V^- = \pm 15V$, $V_{IN} = \pm 1V$, $V_{IN} = 0V$, $T_a = 25^\circ C$



Maximum Output Voltage vs. Load Current

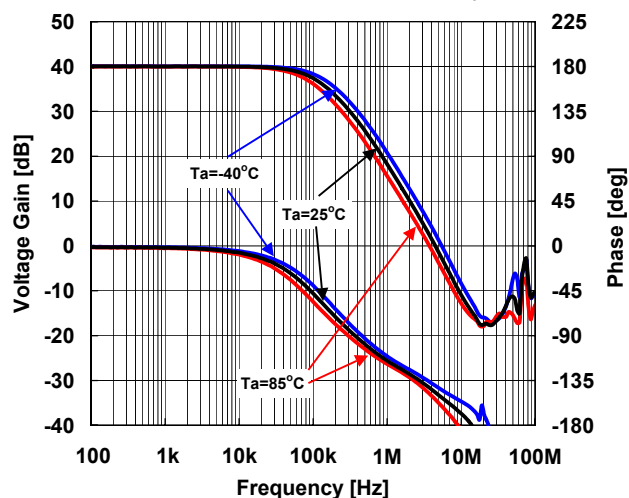
$V^+/V^- = \pm 4.5V$, $V_{IN} = \pm 1V$, $T_a = 25^\circ C$



■ TYPICAL CHARACTERISTICS

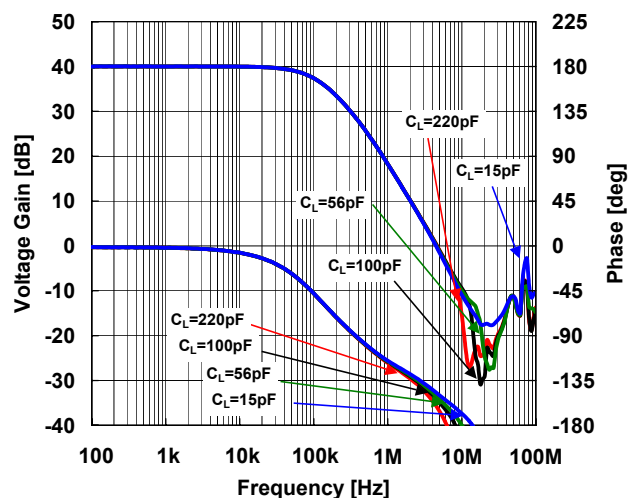
40dB Gain/Phase vs. Frequency (Ambient Temperature)

$V^+/V^- = \pm 15V$, $G_V = 40dB$, $R_I = 50\Omega$, $R_L = 2k\Omega$, $C_L = 15pF$



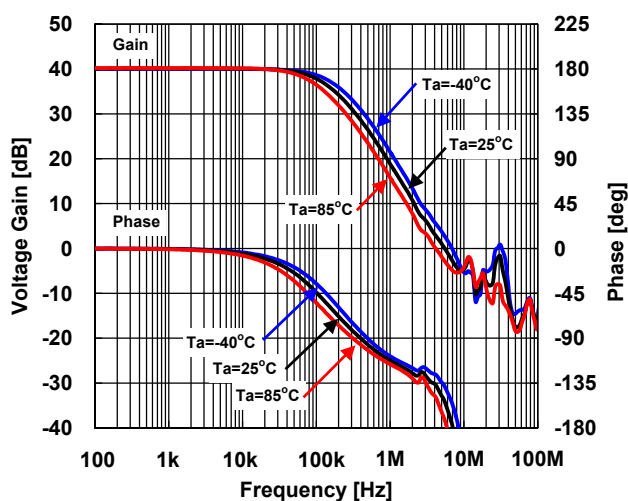
40dB Gain/Phase vs. Frequency (Load Capacitance)

$V^+/V^- = \pm 15V$, $G_V = 40dB$, $R_I = 50\Omega$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



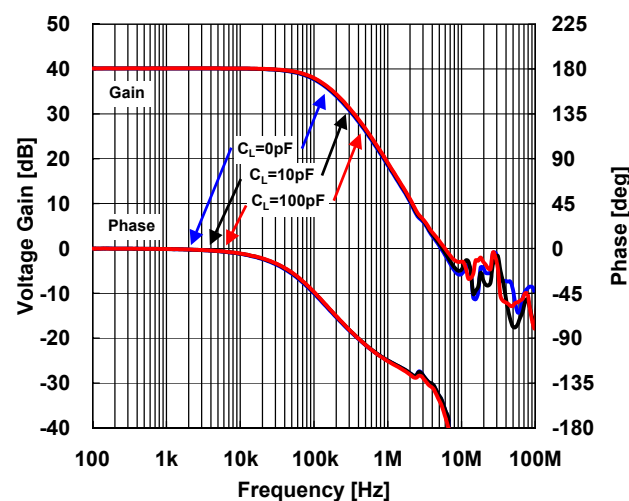
40dB Gain/Phase vs. Frequency (Ambient Temperature)

$V^+/V^- = \pm 4.5V$, $G_V = 40dB$, $R_L = 2k\Omega$, $C_L = 10pF$



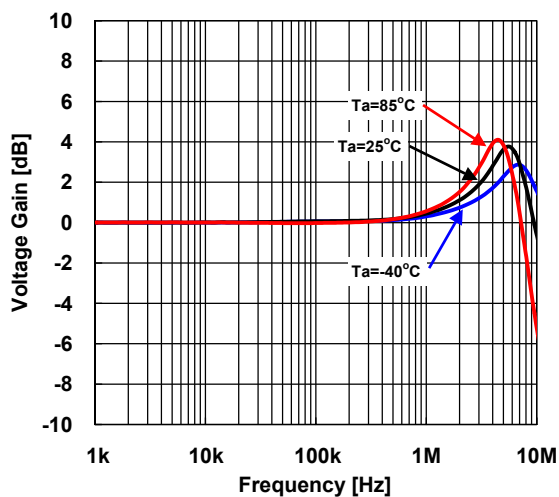
40dB Gain/Phase vs. Frequency (Load Capacitance)

$V^+/V^- = \pm 4.5V$, $G_V = 40dB$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



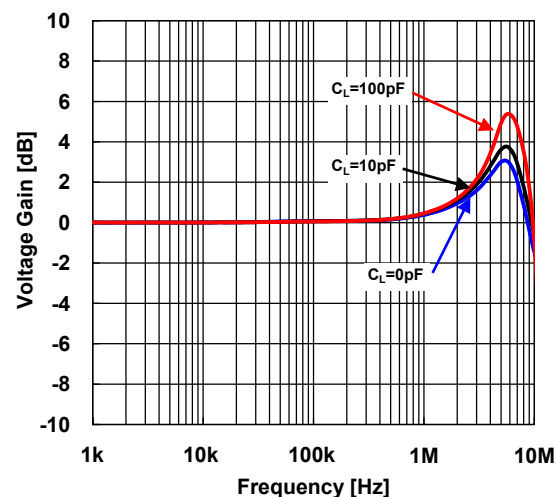
V.F. Peak vs. Frequency (Ambient Temperature)

$V^+/V^- = \pm 4.5V$, $G_V = 0dB$, $R_L = 2k\Omega$, $C_L = 10pF$



V.F. Peak vs. Frequency (Load Capacitance)

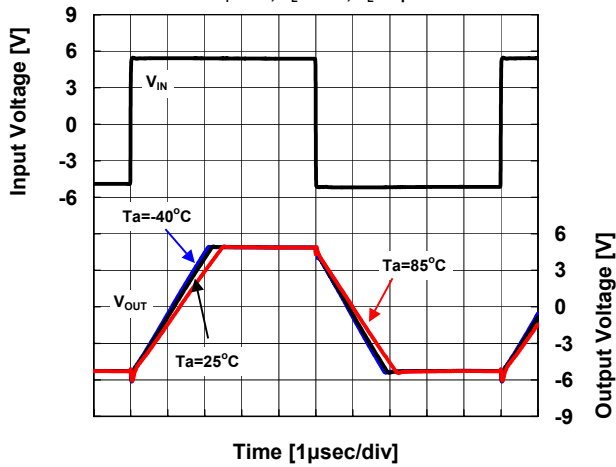
$V^+/V^- = \pm 4.5V$, $G_V = 0dB$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



■ TYPICAL CHARACTERISTICS

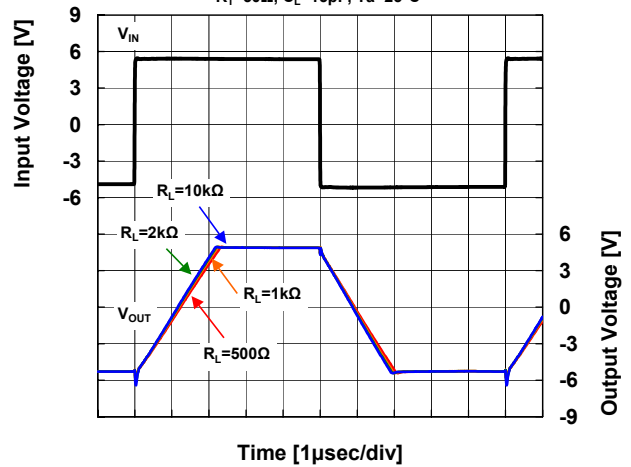
Pulse Response (Ambient Temperature)

$V^+/V^- = \pm 15V$, $V_{IN} = 10V_{PP}$, $f_{IN} = 1kHz$, $G_V = 0dB$,
 $R_T = 50\Omega$, $R_L = 50k\Omega$, $C_L = 15pF$



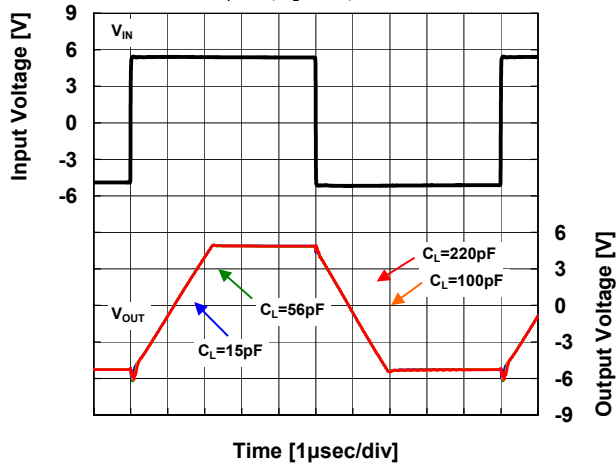
Pulse Response (Load Resistance)

$V^+/V^- = \pm 15V$, $V_{IN} = 10V_{PP}$, $f_{IN} = 1kHz$, $G_V = 0dB$,
 $R_T = 50\Omega$, $C_L = 15pF$, $T_a = 25^\circ C$



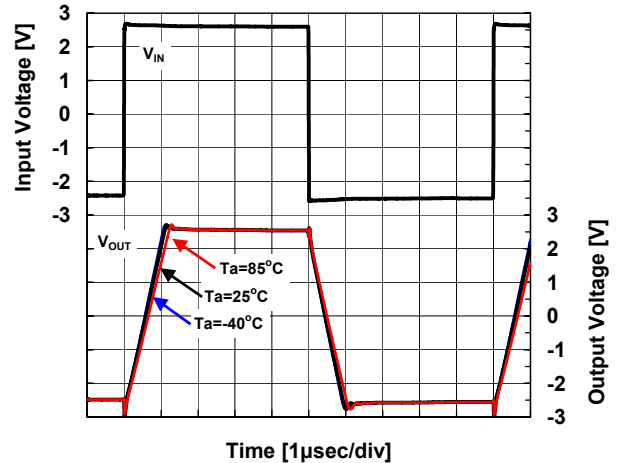
Pulse Response (Load Capacitance)

$V^+/V^- = \pm 15V$, $V_{IN} = 10V_{PP}$, $f_{IN} = 1kHz$, $G_V = 0dB$,
 $R_T = 50\Omega$, $R_L = 50k\Omega$, $T_a = 25^\circ C$



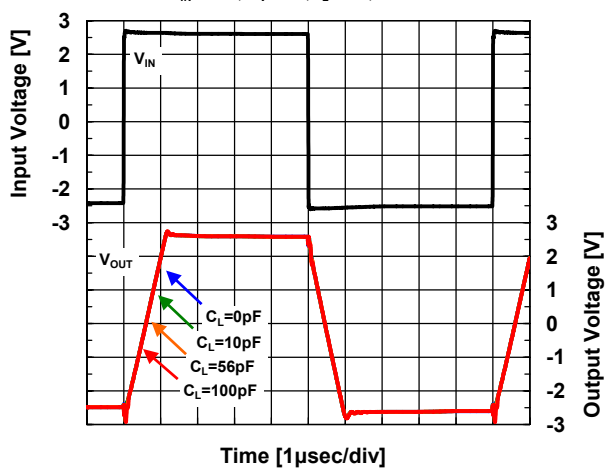
Pulse Response (Ambient Temperature)

$V^+/V^- = \pm 4.5V$, $V_{IN} = \pm 2.5V$,
 $f_{IN} = 1kHz$, $G_V = 0dB$, $R_L = 2k\Omega$, $C_L = 10pF$



Pulse Response (Load Capacitance)

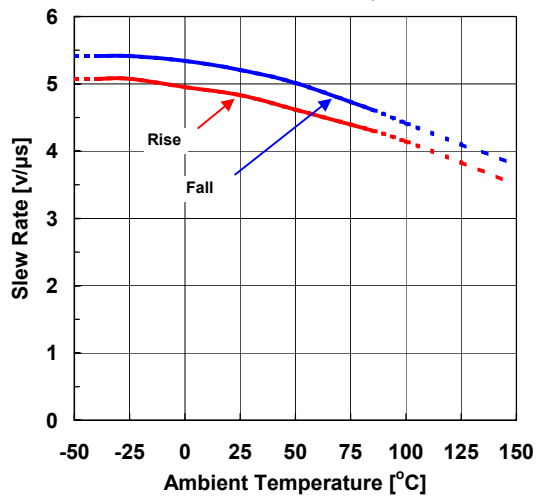
$V^+/V^- = \pm 4.5V$, $V_{IN} = \pm 2.5V$,
 $f_{IN} = 1kHz$, $G_V = 0dB$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



■ TYPICAL CHARACTERISTICS

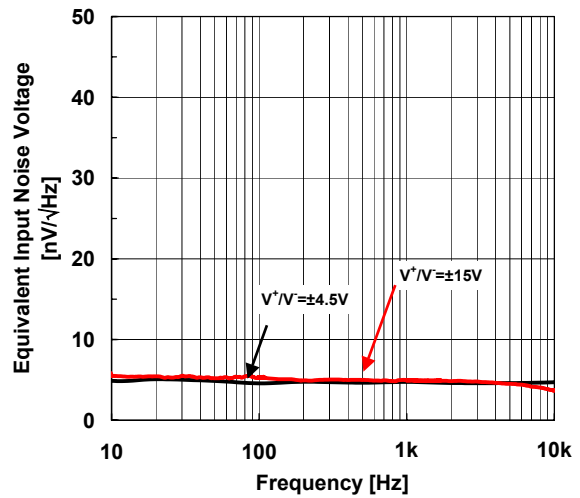
Slew Rate vs. Ambient Temperature

$V^+/V^- = \pm 15V$, $V_{in} = 10V_{pp}$, $f_{in} = 1kHz$, $G_v = 0dB$,
 $R_T = 50\Omega$, $R_L = 2k\Omega$, $C_L = 15pF$



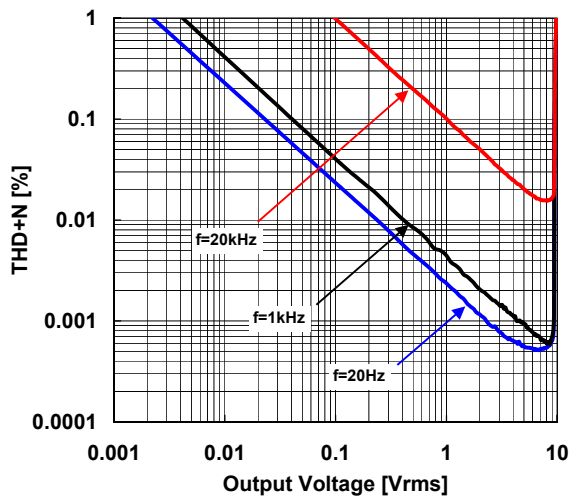
Equivalent Input Noise Voltage

$R_S = 50\Omega$, $R_L = 100k\Omega$, $G_v = 60dB$, $T_a = 25^\circ C$



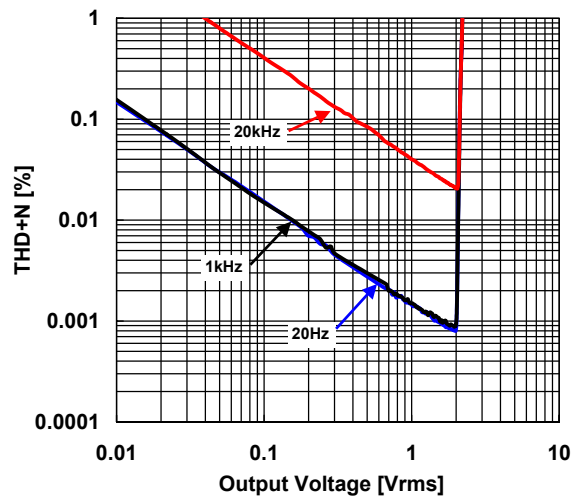
THD+N vs. Output Voltage

$V^+/V^- = \pm 15V$, $G_v = 20dB$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



THD+N vs. Output Voltage

$V^+/V^- = \pm 4.5V$, $G_v = 20dB$, $R_L = 2k\Omega$, $T_a = 25^\circ C$



■ MEMO

[CAUTION]
The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.